

MARSHALL, GERSTEIN & BORUN LLP
ATTORNEYS AT LAW
6300 SEARS TOWER
233 SOUTH WACKER DRIVE
CHICAGO, ILLINOIS 60606-6357
(312) 474-6300
FAX: (312) 474-0448

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MESSAGE:

Serial No.: 10/739,229
Confirmation: 1123
Applicant: Byoung Hee Cho
Filed: December 18, 2003
Title: Method for Forming Gate Oxide in Semiconductor Device
Art Unit: 2812
Examiner: NHU, David
Atty Docket: 29936/39870
Customer No.: 04743

Enclosed is a copy of an Amendment "A" (6 pages).

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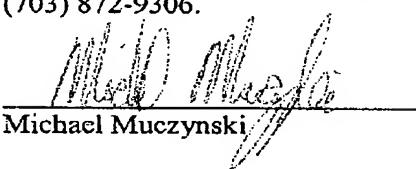
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Serial No. 10/739,229

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**IN THE UNITED STATES PATENT
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Serial No. : 10/739,229) Date of Transmittal:
Confirmation : 1123) June 2, 2005
)
Applicant : Byoung Hee Cho) I hereby certify that this paper and all
Filed : December 18, 2003) documents referred to herein as being enclosed
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Title: METHOD FOR FORMING) Patent and Trademark Office, Mail Stop
GATE OXIDE IN SEMICONDUCTOR) Amendment via facsimile to facsimile number
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Art Unit : 2812)
Examiner : NHU, David)
)
Atty Docket : 29936/39870)
Customer No. : 04743)


Michael Muczynski

AMENDMENT "A"

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Please amend this application as specified on the following pages.